**Analog Power AM7400N** 

## N-Channel 30-V (D-S) MOSFET

### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

### **Typical Applications:**

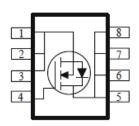
- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I <sub>D</sub> (A)	
30	2.5 @ V <sub>GS</sub> = 10V	36.6	
30	$4 @ V_{GS} = 4.5V$	28.9	

DFN5X6-8L







ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Limit	Units				
Drain-Source Voltage			30	V			
Gate-Source Voltage	$V_{GS}$	±20	٧				
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C		36.6				
Continuous Drain Current	T <sub>A</sub> =70°C	· I <sub>D</sub>	29.3	Α			
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	100				
Continuous Source Current (Diode Conduction) a		I <sub>S</sub>	7.1	Α			
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{D}$	5	W			
Fower Dissipation	T <sub>A</sub> =70°C	'D	3.2	VV			
Operating Junction and Storage Temperature Range		$T_J$ , $T_{stg}$	-55 to 150	°C			

THERMAL RESISTANCE RATINGS							
Parameter			Maximum	Units			
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	$R_{\theta JA}$	25	°C/W			
Maximum Junction-to-Ambient	Steady State	IΛθJA	65	C/VV			

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#### Notes

- Surface Mounted on 1" x 1" FR4 Board. a.
- b. Pulse width limited by maximum junction temperature

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#### **Electrical Characteristics**

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Brain Garrent	I <sub>DSS</sub>	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α	
Drain-Source On-Resistance	r <sub>no( )</sub>	$V_{GS} = 10 \text{ V}, I_D = 26 \text{ A}$			2.5	mΩ	
Diam-Source On-Nesistance	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 23.2 \text{ A}$			4	11122	
Forward Transconductance	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 20 \text{ A}$		40		S	
Diode Forward Voltage	$V_{SD}$	$I_S = 3.6 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
		Dynamic					
Total Gate Charge	$Q_g$			65			
Gate-Source Charge	$Q_gs$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		17		nC	
Gate-Drain Charge	$Q_gd$			36			
Turn-On Delay Time	t <sub>d(on)</sub>			18			
Rise Time	t <sub>r</sub>	$V_{DS} = 15 \text{ V}, R_L = 0.8 \Omega, I_D = 20 \text{ A},$		106		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		191			
Fall Time	t <sub>f</sub>			108			
Input Capacitance	$C_{iss}$			6813			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		1166		pF	
Reverse Transfer Capacitance	$C_{rss}$			766			

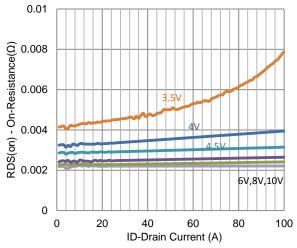
#### Notes

- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

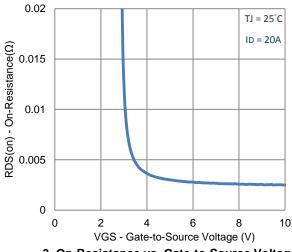
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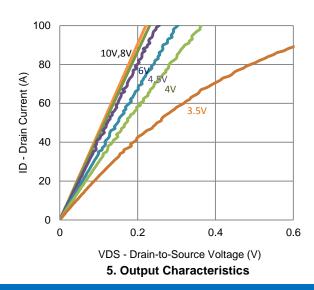
### **Typical Electrical Characteristics**



#### 1. On-Resistance vs. Drain Current

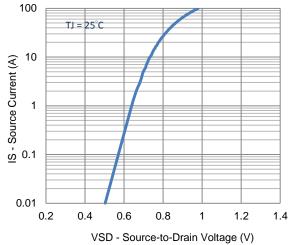


3. On-Resistance vs. Gate-to-Source Voltage

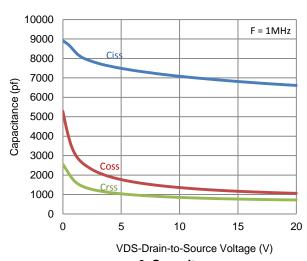


100  $TJ = 25^{\circ}C$ 80 ID - Drain Current (A) 60 40 20 0 0 1 2 3 4 5 VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics



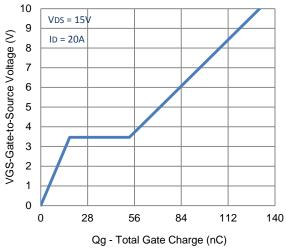
4. Drain-to-Source Forward Voltage

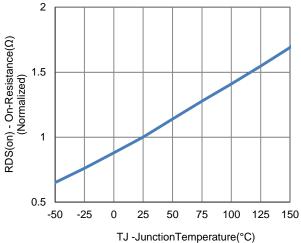


6. Capacitance

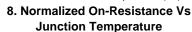
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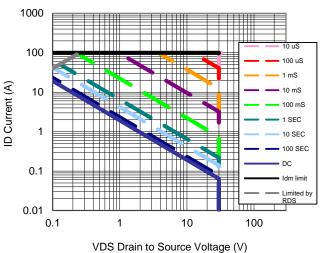
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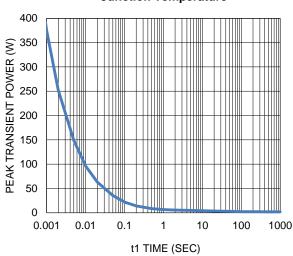




7. Gate Charge

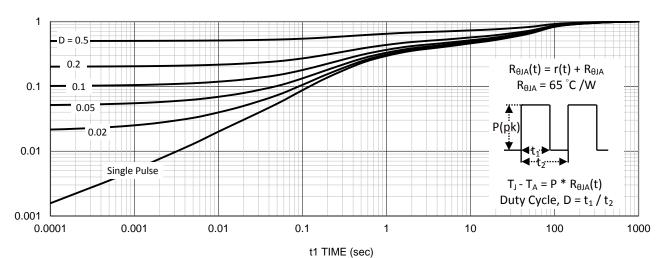






9. Safe Operating Area

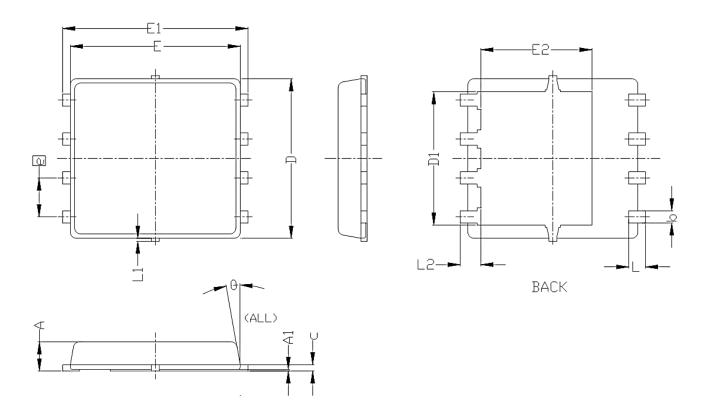
10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

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# Package Information



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
STMBULS	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.85	0.95	1.00	0.033	0.037	0.039	
Al	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
С	0. 15	0.20	0. 25	0.006	0.008	0.010	
D	5, 20 BSC			0. 205 BSC			
D1	4. 35 BSC			0. 171 BSC			
E	5, 55 BSC			0. 219 BSC			
E1	6. 05 BSC			0. 238 BSC			
E2	3. 62 BSC			0. 143 BSC			
e	1. 27 BSC			0.050 BSC			
L	0.45	0.55	0.65	0.018	0.022	0.026	
L1	0		0.15	0		0.006	
L2	0.68 REF			0. 027 REF			
θ	0°		10°	0°		10°	